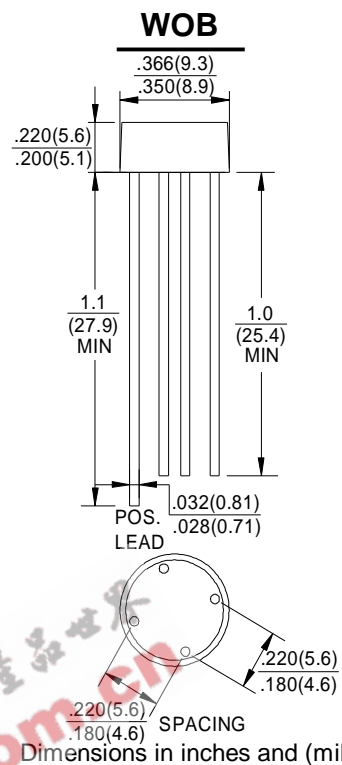


SILICON BRIDGE RECTIFIERS	REVERSE VOLTAGE - 50 to 1000Volts FORWARD CURRENT - 2.0 Amperes
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FEATURES

- Surge overload rating -60 amperes peak
- Ideal for printed circuit board
- Reliable low cost construction utilizing molded plastic technique results in expensive product
- Mounting position :Any
- Lead: Sliver plated copper lead



MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Rating at 25°C ambient temperature unless otherwise specified.
 Single phase, half wave ,60Hz, resistive or inductive load.
 For capacitive load, derate current by 20%

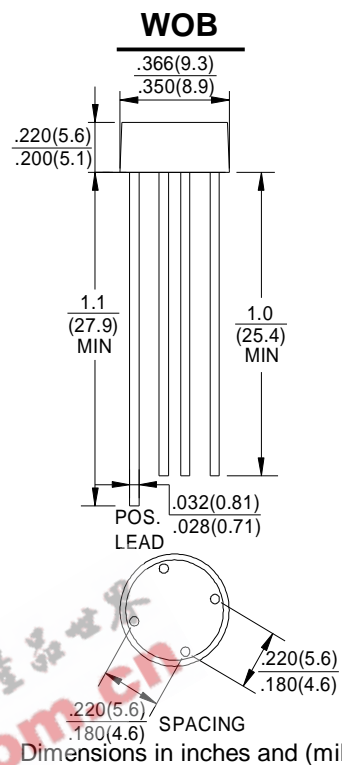
CHARACTERISTICS	SYMBOL	2W005	2W01	2W02	2W04	2W06	2W08	2W10	UNIT
Maximum Recurrent Peak Reverse Voltage	VRRM	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	VDC	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current 0.375" (9.5mm) Lead Lengths @TA=25 °C	I(AV)	2.0							A
Peak Forward Surge Current , 8.3ms Single Half Sine-Wave Super Imposed on Rated Load (JEDEC Method)	IFSM	60							A
I ² t Rating for Fusing (t<8.3ms)	I ² t	15.0							A ² s
Maximum Forward Voltage Drop Per Element at 2.0A Peak	VF	1.1							V
Maximum DC Reverse Current at Rated DC Blocking Voltage TA=25°C	IR	10.0							uA
		1.0							mA
Typical Junction Capacitance Per Element (Note1)	CJ	30							pF
Operating Temperature Range	TJ	-55 to +125							°C
Storage Temperature Range	TSTG	-55 to +125							°C

Note:1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

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